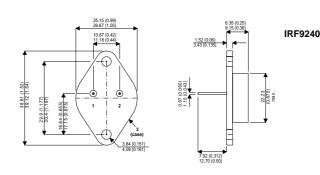


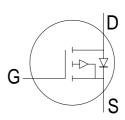
# **IRF9240 IRFN9240** IRF9240SMD

### **MECHANICAL DATA**

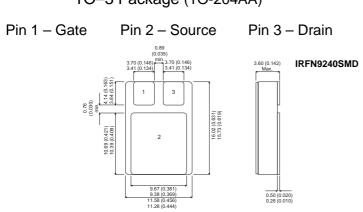
Dimensions in mm (inches)



# **P-CHANNEL POWER MOSFET**



TO-3 Package (TO-204AA)



SMD1 (TO276AB)

Pin 1 - Gate

Pin 2 - Drain

Pin 3 - Source

### **FEATURES**

- P-CHANNEL POWER MOSFET
- HIGH VOLTAGE
- INTEGRAL PROTECTION DIODE
- AVAILABLE IN TO-3 (TO-204AA) AND **CERAMIC SURFACE MOUNT SMD1** (TO276AB)PACKAGE

Note: IRF9240SMD also available with pins 1 and 3 reversed on SMD 1 package.

## **ABSOLUTE MAXIMUM RATINGS** (T<sub>case</sub> = 25°C unless otherwise stated)

$V_{DSS}$	Drain – Source Voltage		–200V
$V_{DGR}$	Drain – Gate Voltage ( $R_{GS} = 20K\Omega$ )		-200V
$V_{GS}$	Gate – Source Voltage		±20V
I <sub>D</sub>	Continuous Drain Current	@ T <sub>case</sub> = 25°C	-11A
		@ T <sub>case</sub> = 100°C	–7.0A
$I_{DM}$	Pulsed Drain Current		-44A
$P_{D}$	Max. Power Dissipation	@ T <sub>case</sub> = 25°C	125W
	Linear Derating Factor		1W / °C
T <sub>j</sub>	Operating Junction and		−55 to 150°C
T <sub>stg</sub>	Storage Temperature Range		_55 to 150 C

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# IRF9240 IRFN9240 IRF9240SMD

# **ELECTRICAL RATINGS** (T<sub>case</sub> = 25°C unless otherwise stated)

	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain – Source Breakdown Voltage	$V_{GS} = 0V$ , $I_D = -1mA$	-200			V
V <sub>GS(TH)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$	-2		-4	V
I <sub>GSS</sub>	Gate – Source Leakage Current (forward)	V <sub>GS</sub> = −20V			-100	nA
	Gate – Source Leakage Current (reverse)	V <sub>GS</sub> = 20V			100	nA
	Zero Gate Voltage Drain Current	$V_{DS} = -160V , V_{GS} = 0V$			-25	μΑ
I <sub>DSS</sub>		V <sub>DS</sub> = -160V			-1	mA
		V <sub>GS</sub> = 0V , T <sub>case</sub> = 125°C			-1	
1	On State Drain Current <sup>1</sup>	$V_{DS} > I_{D(ON)} \times R_{DS(ON)} Max$	-11			Α
I <sub>D(ON)</sub>		$V_{GS} = -10V$	-''			^
R <sub>DS(ON)</sub>	Static Drain – Source On-State Resistance	$V_{GS} = -10V , I_{D} = -7A$		0.35	0.5	Ω
α.	Forward Transconductance <sup>1</sup>	$V_{DS} > I_{D(ON)} \times R_{DS(ON)} Max$	4	6		S
g <sub>fs</sub>		$I_D = -7A$				
C <sub>iss</sub>	Input capacitance	V <sub>GS</sub> = 0V		1200		
C <sub>oss</sub>	Output capacitance	$V_{DS} = -25V$		570		pF
C <sub>rss</sub>	Reverse transfer capacitance	f = 1MHz		81		
Qg	Total Gate Charge	V <sub>GS</sub> = −10V	28		60	
Q <sub>gs</sub>	Gate – Source Charge	I <sub>D</sub> = -11A	3.0		15	nC
Q <sub>gd</sub>	Gate - Drain ("Miller") Charge	V <sub>DS</sub> = -100V	4.5		38	
t <sub>d(on)</sub>	Turn-on Delay Time	1001			35	
t <sub>r</sub>	Rise Time	$V_{DD} = -100V$			85	-
t <sub>d(off)</sub>	Turn-off Delay Time	I <sub>D</sub> = -11A			85	ns
t <sub>f</sub>	Fall Time	$Z_{O} = 9.1\Omega$			65	1
L <sub>D</sub>	Internal Drain Inductance			5.0		nΗ
L <sub>S</sub>	Internal Source Inductance			12.5		nΗ

#### THERMAL CHARACTERISTICS

	Characteristic		Min.	Тур.	Max.	Unit
$R_{\theta JC}$	Junction to Case				1.0	°C/W
$R_{\theta JA}$	Junction to Ambient	(TO-3 package only)			30	°C/W
TL	Max. Lead Temperature 0.063" from case for 10 sec.	(TO-3 package only)		300		°C

### **SOURCE – DRAIN DIODE RATINGS AND CHARACTERISTICS**

Characteristic	Test Conditions	Min.	Тур.	Max.	Unit	
Continuous Source Current (Body Diode)				-11	Α	
Pulsed Source Current <sup>1</sup> (Body Diode)				-44	A	
Diode Forward Voltage <sup>2</sup>	$V_{GS} = 0V$ , $I_S = -11A$ $T_{case} = 25^{\circ}C$			-4.6	V	
Reverse Recovery Time	$I_F = -11A$ , $dI_F / dt = 100A/μs$ $T_j = 25°C$		270		ns	
Reverse Recovery Charge	$I_F = -11A$ , $dI_F / dt = 100A/μs$ $T_j = 25°C$		2.0		μC	
	Continuous Source Current (Body Diode) Pulsed Source Current <sup>1</sup> (Body Diode) Diode Forward Voltage <sup>2</sup> Reverse Recovery Time	Continuous Source Current (Body Diode)  Pulsed Source Current (Body Diode)  Diode Forward Voltage $^2$ Reverse Recovery Time $V_{GS} = 0V$ , $I_S = -11A$ $V_{Case} = 25^{\circ}C$ $I_F = -11A$ , $dI_F/dt = 100A/\mu s$ $V_{GS} = 0V$ , $I_S = -11A$ $V_{Case} = 25^{\circ}C$ $V_{GS} = 0V$ , $V_{GS} = $	Continuous Source Current (Body Diode)  Pulsed Source Current (Body Diode)  Diode Forward Voltage <sup>2</sup> Reverse Recovery Time $V_{GS} = 0V$ , $I_{S} = -11A$ $T_{case} = 25^{\circ}C$ $I_{F} = -11A$ , $dI_{F}/dt = 100A/\mu s$ $T_{j} = 25^{\circ}C$ Reverse Recovery Charge	Continuous Source Current (Body Diode)  Pulsed Source Current <sup>1</sup> (Body Diode)  Diode Forward Voltage <sup>2</sup> Reverse Recovery Time $V_{GS} = 0V$ , $I_{S} = -11A$ $T_{case} = 25^{\circ}C$ $I_{F} = -11A$ , $dI_{F}/dt = 100A/\mu s$ $T_{j} = 25^{\circ}C$ Reverse Recovery Charge $I_{F} = -11A$ , $dI_{F}/dt = 100A/\mu s$ 270	Continuous Source Current (Body Diode)  Pulsed Source Current <sup>1</sup> (Body Diode) $V_{GS} = 0 \text{ V}, \text{ I}_{S} = -11 \text{ A}$ $T_{case} = 25^{\circ}\text{ C}$ Reverse Recovery Time $I_{F} = -11 \text{ A}, \text{ dI}_{F}/\text{ dt} = 100 \text{ A}/\mu\text{s}$ $T_{j} = 25^{\circ}\text{ C}$ Reverse Recovery Charge $I_{F} = -11 \text{ A}, \text{ dI}_{F}/\text{ dt} = 100 \text{ A}/\mu\text{s}$ $T_{j} = 25^{\circ}\text{ C}$	

<sup>1)</sup> Pulse Test: Pulse Width <  $300\mu S$  , Duty Cycle  $\leq 2\%$  2) Repetitive Rating: Pulse Width limited by maximum junction temperature.

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